

32nd RD50 Workshop (Hamburg)

Monday 4 June 2018

Device Simulation - Auditorium (15:00 - 17:30)

time	[id] title	presenter
15:00	[14] TCAD Process and device simulation of OVERMOS, a CMOS 180nm MAPS detector	VILLANI, Enrico Giulio
15:20	[20] ILGAD TCAD Simulations	Prof. PALOMO PINTO, Fco.Rogelio
15:40	Coffee Break	
16:10	[11] A new model for the TCAD simulation of the silicon damage by high fluence proton irradiation	Dr SCHWANDT, Joern
16:30	[8] Overview of sensor simulation session at LHC inter-experiment workshop	NACHMAN, Ben
17:00	[33] Discussion	SCHWANDT, Joern